

# HSM88AS

# Silicon Schottky Barrier Diode for Balanced Mixer

REJ03G0135-0600Z

(Previous: ADE-208-046E)

Rev.6.00

Nov.06.2003

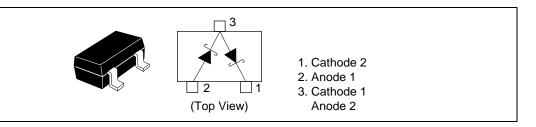
#### **Features**

- Proof against high voltage.
- MPAK package is suitable for high density surface mounting and high speed assembly.

#### **Ordering Information**

Type No.	Laser Mark	Package Code
HSM88AS	C1	MPAK

#### **Pin Arrangement**



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit	
Reverse voltage	$V_R$	10	V	
Average rectified current	lo*1	15	mA	
Junction temperature	Tj	125	°C	
Storage temperature	Tstg	-55 to +125	°C	

Note: 1. Per one device

## **Electrical Characteristics** \*1

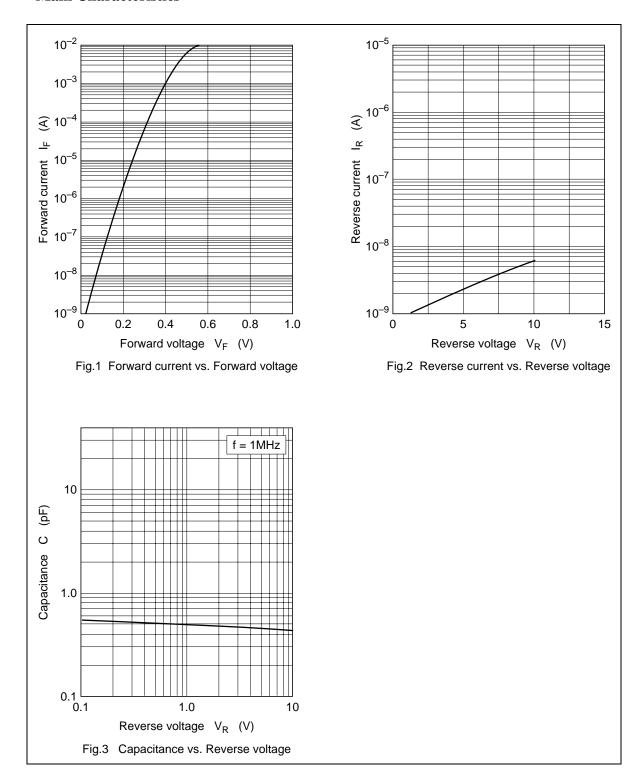
 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	$V_{F1}$	0.35	_	0.42	V	I <sub>F</sub> = 1 mA
	V <sub>F2</sub>	0.50	_	0.58	='	I <sub>F</sub> = 10 mA
Reverse current	I <sub>R1</sub>	_	_	0.2	μΑ	V <sub>R</sub> = 2 V
	I <sub>R2</sub>	_	_	10	='	V <sub>R</sub> = 10 V
Capacitance	С	_	_	0.85	pF	V <sub>R</sub> = 0 V, f = 1 MHz
Capacitance deviation	ΔC	_	_	0.10	рF	V <sub>R</sub> = 0 V, f = 1 MHz
Forward voltage deviation	$\Delta V_{F}$	_	_	10	mV	I <sub>F</sub> = 10 mA
ESD-Capability *2	_	30	_	_	V	$C = 200 \text{ pF}, R = 0 \Omega$ , Both forward and reverse direction 1 pulse.

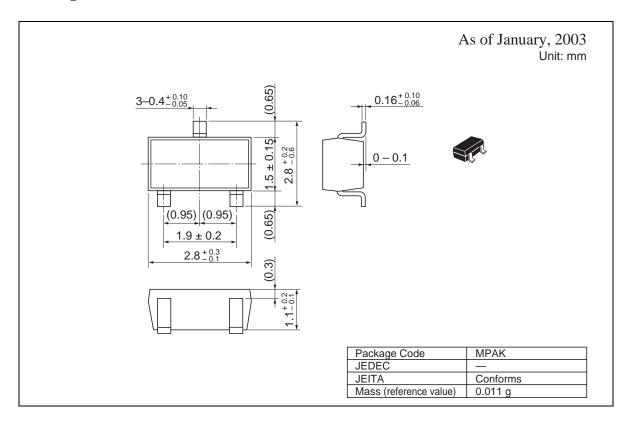
Notes: 1. Per one device

2. Failure criterion ;  $I_R \geq 0.4~\mu\text{A}$  at  $V_R$  = 2 V

#### **Main Characteristics**



### **Package Dimensions**



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